## $25 \mu \mathrm{~V}, 0.3 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}$, Low Noise Instrumentation Amplifier DESCRIPTIOn

The $\mathrm{LT}^{\circledR} 6370$ is a gain programmable, high precision instrumentation amplifier that delivers industry leading DC precision. This high precision enables smaller signals to be sensed and eases calibration requirements, particularly over temperature.

The LT6370 uses a proprietary high performance bipolar process which enables industry leading accuracy coupled with exceptional long-term stability. The LT6370 is laser trimmed for very low input offset voltage $(25 \mu \mathrm{~V})$ and high CMRR (94dB, G = 1). Proprietary on-chip test capability allows the input offset voltage drift $\left(0.3 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}\right)$ and gain drift $\left(30 \mathrm{ppm} /{ }^{\circ} \mathrm{C}\right)$ to be guaranteed with automated testing on the S8E package.

In addition to excellent DC specifications, the LT6370's wide bandwidth $(3.1 \mathrm{MHz}, \mathrm{G}=1)$ and fast settling time allow it to operate well in multiplexed applications. EMI filtering is integrated on the LT6370's inputs to maintain accuracy in the presence of harsh RF interference.

The LT6370 is available in a compact 8-pin MSOP or S8E which use the conventional instrumentation amplifier pin-out as well as a 10 -pin $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ DFN. The S8E package is also offered as an A grade which has superior DC specifications. The LT6370 is fully specified over the $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ and $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ temperature ranges.

All registered trademarks and trademarks are the property of their respective owners.

## TYPICAL APPLICATION



PRECISION BRIDGE TRANSDUCER

LT6370A MONOLITHIC INSTRUMENTATION AMPLIFIER $G=100, R_{G}= \pm 0.1 \%, \pm 10 \mathrm{ppm}$ TC

Distribution of Input Offset Voltage Drift, MS8 Package


## LT6370

## ABSOLUTG MAXIMUM RATINGS

(Note 1)
Total Supply Voltage ( $\mathrm{V}^{+}$to $\mathrm{V}^{-}$)................................ 36 V
Input Voltage (+IN, -IN, $\left.+R_{G},-R_{G}, R E F\right)$ $\qquad$ $\left(\mathrm{V}^{-}-0.3 \mathrm{~V}\right)$ to $\left(\mathrm{V}^{+}+0.3 \mathrm{~V}\right)$
Differential Input Voltage (+IN to -IN).................... $\pm 36 \mathrm{~V}$
Input Current ( $+\mathrm{R}_{\mathrm{G}},-\mathrm{R}_{\mathrm{G}}$ ) ...................................... $\pm 2 \mathrm{~mA}$

## Input Current (+IN, -IN) $\ldots . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . ~ \pm 10 m A ~$

 Input Current (REF) ............................................-10mA Output Short-Circuit Duration .............Thermally LimitedOutput Current ..... 80 mA
Operating and Specified Temperature Range$-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$
H-Grade ..... $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$
Maximum Junction Temperature ..... $150^{\circ} \mathrm{C}$
Storage Temperature Range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$
Lead Temperature (Soldering, 10 sec ). ..... $300^{\circ} \mathrm{C}$

## PIn CONFIGURATIOn

|  | TOP VIEW | TOP VIEW |
| :---: | :---: | :---: |
|  | 10-LEAD $(3 \mathrm{~mm} \times 3 \mathrm{~mm})$ PLASTIC DFN $\theta_{\mathrm{JA}}=43^{\circ} \mathrm{C} / \mathrm{W}, \theta_{\mathrm{JC}}=5.5^{\circ} \mathrm{C} / \mathrm{W}$ <br> EXPOSED PAD (PIN 11) IS CONNECTED TO $\mathrm{V}^{-}$(PIN 5) (PCB CONNECTION OPTIONAL) | EXPOSED PAD (PIN 9) MUST FLOAT <br> OR BE CONNECTED TO $\mathrm{V}^{+}$IN ADDITION TO PIN 7 |

## ORDER INFORMATION

| TUBE | TAPE AND REEL | PART MARKING* | PACKAGE DESCRIPTION | TEMPERATURE RANGE |
| :---: | :---: | :---: | :---: | :---: |
| LT6370IS8E\#PBF | LT6370IS8E\#TRPBF | 6370 | 8-Lead Plastic SO | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| LT6370HS8E\#PBF | LT6370HS8E\#TRPBF | 6370 | 8-Lead Plastic SO | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT6370IMS8\#PBF | LT6370IMS8\#TRPBF | LTGZP | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| LT6370HMS8\#PBF | LT6370HMS8\#TRPBF | LTGZP | 8-Lead Plastic MSOP | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT6370IDD\#PBF | LT6370IDD\#TRPBF | LGZN | 10-Lead ( $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ ) Plastic DFN | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| LT6370HDD\#PBF | LT6370HDD\#TRPBF | LGZN | 10-Lead (3mm $\times 3 \mathrm{~mm}$ ) Plastic DFN | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |
| LT6370AIS8E\#PBF | LT6370AIS8E\#TRPBF | 6370 | 8-Lead Plastic SO | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ |
| LT6370AHS8E\#PBF | LT6370AHS8E\#TRPBF | 6370 | 8-Lead Plastic SO | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |

Contact the factory for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.
Tape and reel specifications. Some packages are available in 500 unit reels through designated sales channels with \#TRMPBF suffix.

## ELECTRICAL CHARACT $\in$ RISTICS The denotes the specifications which apply over the specified

temperature range, otherwise specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} . \mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$.

| SYMBOL | PARAMETER | CONDITIONS |  | LT6370A |  |  | LT6370 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| G | Gain Range | $\mathrm{G}=\left(1+24.2 \mathrm{k} / \mathrm{R}_{\mathrm{G}}\right)$ (Note 2) |  | 1 |  | 1000 | 1 |  | 1000 | V/N |
|  | Gain Error (Notes 3, 4) | $\begin{aligned} & G=1 \\ & G=1 \\ & G=10 \\ & G=10, T_{A}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & G=10, T_{A}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \\ & G=100 \\ & G=100, T_{A}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & G=100, T_{A}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \\ & G=1000 \\ & G=1000, T_{A}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & G=1000, T_{A}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ |  |  | $\begin{aligned} & -0.004 \\ & -0.02 \\ & -0.02 \\ & -0.05 \end{aligned}$ | $\begin{gathered} 0.01 \\ 0.02 \\ 0.08 \\ 0.4 \\ 0.58 \\ 0.08 \\ 0.4 \\ 0.58 \\ 0.15 \\ 0.47 \\ 0.65 \\ \hline \end{gathered}$ |  | $\begin{aligned} & \hline-0.004 \\ & -0.02 \\ & -0.02 \\ & -0.05 \end{aligned}$ | 0.015 <br> 0.025 <br> 0.1 <br> 0.42 <br> 0.6 <br> 0.1 <br> 0.42 <br> 0.6 <br> 0.2 <br> 0.52 <br> 0.7 | \% $\%$ $\%$ $\%$ $\%$ $\%$ $\%$ $\%$ $\%$ $\%$ $\%$ |
|  | Gain vs Temperature (Notes 3, 4) | $\begin{aligned} & G=1 \text { (Note 5) } \\ & G>1 \text { (Note 6) } \\ & \hline \end{aligned}$ |  |  | $\begin{aligned} & 0.2 \\ & 20 \end{aligned}$ | $\begin{aligned} & \hline 0.5 \\ & 30 \end{aligned}$ |  | $\begin{aligned} & 0.2 \\ & 20 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 50 \end{aligned}$ | $\begin{aligned} & \mathrm{ppm} /{ }^{\circ} \mathrm{C} \\ & \mathrm{ppm} /{ }^{\circ} \mathrm{C} \end{aligned}$ |
|  | Gain Nonlinearity (Notes 3, 7) | $\begin{aligned} & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=1 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=1 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=10 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=10 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=100 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=100 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, G=1000 \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, \mathrm{G}=1000 \end{aligned}$ |  |  | 1 <br> 3 <br> 20 <br> 50 | $\begin{gathered} 3 \\ 6 \\ 20 \\ 65 \\ 30 \\ 105 \\ 200 \\ 270 \end{gathered}$ |  | 1 <br> 3 <br> 20 <br> 50 | $\begin{gathered} \hline 5 \\ 8 \\ 30 \\ 75 \\ 55 \\ 130 \\ 300 \\ 370 \end{gathered}$ | ppm ppm ppm ppm ppm ppm ppm ppm |
|  |  | $\begin{aligned} & V_{\text {OUT }}= \pm 10 \mathrm{~V}, \mathrm{G}=1, \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, \mathrm{G}=10, \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, \mathrm{G}=100, \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & V_{\text {OUT }}= \pm 10 \mathrm{~V}, \mathrm{G}=1000, \mathrm{R}_{\mathrm{L}}=600 \Omega \end{aligned}$ |  |  | $\begin{gathered} 4 \\ 6 \\ 30 \\ 250 \end{gathered}$ |  |  | $\begin{gathered} 4 \\ 6 \\ 30 \\ 250 \end{gathered}$ |  | ppm ppm ppm ppm |

$\mathrm{V}_{\text {OST }}$, Total Input Referred Offset Voltage, $\mathrm{V}_{\text {OST }}=\mathrm{V}_{\text {OSI }}+\mathrm{V}_{\text {OSO }} / \mathrm{G}$

| $\mathrm{V}_{\text {OSI }}$ | Input Offset Voltage (Note 8) | S8E Package <br> MS8 Package <br> DD10 Package <br> S8E Package, $T_{A}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ <br> MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ <br> DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | $\pm 9$ | $\begin{aligned} & \pm 25 \\ & \\ & \pm 100 \\ & \pm 125 \end{aligned}$ | $\begin{gathered} \pm 15 \\ \pm 8 \\ \pm 15 \end{gathered}$ | $\begin{aligned} & \pm 55 \\ & \pm 35 \\ & \pm 60 \\ & \pm 130 \\ & \pm 155 \\ & \pm 125 \\ & \pm 150 \\ & \pm 155 \\ & \pm 180 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {OSO }}$ | Output Offset Voltage (Note 8) | S8E Package <br> MS8 Package <br> DD10 Package <br> S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ <br> MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ <br> DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ <br> DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ | $\begin{aligned} & \bullet \\ & \bullet \\ & \bullet \\ & \bullet \\ & \bullet \\ & \bullet \end{aligned}$ | $\pm 60$ | $\begin{aligned} & \pm 165 \\ & \pm 390 \\ & \pm 515 \end{aligned}$ | $\begin{aligned} & \pm 70 \\ & \pm 30 \\ & \pm 45 \end{aligned}$ | $\begin{aligned} & \pm 265 \\ & \pm 150 \\ & \pm 250 \\ & \pm 490 \\ & \pm 615 \\ & \pm 325 \\ & \pm 400 \\ & \pm 510 \\ & \pm 650 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \\ & \mu \mathrm{~V} \end{aligned}$ |
| $\overline{\mathrm{V}_{\text {OSI }} / T}$ | Input Offset Voltage Drift (Notes 5, 8) | S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ MS8 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  |  | $\begin{aligned} & \pm 0.3 \\ & \pm 0.4 \end{aligned}$ |  | $\begin{aligned} & \pm 0.4 \\ & \pm 0.5 \\ & \pm 0.3 \\ & \pm 0.4 \\ & \pm 0.4 \\ & \pm 0.5 \end{aligned}$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | Input Offset Voltage Hysteresis (Note 9) | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ | $\bullet$ | $\begin{gathered} \pm 1.5 \\ \pm 3 \end{gathered}$ |  | $\begin{gathered} \pm 1.5 \\ \pm 3 \end{gathered}$ |  | $\mu \mathrm{V}$ $\mu \mathrm{V}$ |

ELECTRICAL CHARACTGRISTICS The $\bullet$ denotes the specifications which apply over the speciified
temperature range, otherwise specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} . \mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$.

| SYMBOL | PARAMETER | CONDITIONS |  | LT6370A |  |  | LT6370 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| V ${ }_{\text {OSO}} / \mathrm{T}$ | Output Offset Voltage Drift (Notes 5, 8) | S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ S8E Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ MS8 Package, $T_{A}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ MS8 Package, $T_{A}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ DD10 Package, $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ | $\bullet$  <br> $\bullet$  <br> $\bullet$  <br> $\bullet$  <br> $\bullet$  <br> $\bullet$  |  |  | $\begin{aligned} & \pm 1.5 \\ & \pm 1.5 \end{aligned}$ |  |  | $\begin{gathered} \pm 2.5 \\ \pm 3.5 \\ \pm 2 \\ \pm 2.5 \\ \pm 3 \\ \pm 4 \\ \hline \end{gathered}$ | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | Output Offset Voltage Hysteresis (Note 9) | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ |  |  | $\begin{aligned} & \pm 10 \\ & \pm 20 \end{aligned}$ |  |  | $\begin{aligned} & \pm 10 \\ & \pm 20 \end{aligned}$ |  | $\mu \mathrm{V}$ $\mu \mathrm{V}$ |
| $\mathrm{I}_{B}$ | Input Bias Current | MS8 and S8E Packages DD10 Package <br> $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$, MS8 and S8E Packages <br> $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}, \mathrm{DD10}$ Package <br> $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, MS8 and S8E Packages <br> $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, DD10 Package |  |  | $\pm 0.1$ | $\begin{aligned} & \pm 0.4 \\ & \pm 1.3 \\ & \pm 2.8 \end{aligned}$ |  | $\begin{aligned} & \pm 0.1 \\ & \pm 0.1 \end{aligned}$ | $\begin{gathered} \pm 0.6 \\ \pm 0.8 \\ \pm 1.5 \\ \pm 1.7 \\ \pm 3 \\ \pm 3.2 \end{gathered}$ | nA nA nA nA nA nA |
| IOS | Input Offset Current | MS8 and S8E Packages DD10 Package MS8 and S8E Packages DD10 Package | $\begin{aligned} & \bullet \\ & \bullet \\ & \hline \end{aligned}$ |  | $\pm 0.2$ | $\begin{aligned} & \pm 0.7 \\ & \pm 1.7 \end{aligned}$ |  | $\begin{aligned} & \pm 0.2 \\ & \pm 0.2 \end{aligned}$ | $\begin{gathered} \pm 1 \\ \pm 1.4 \\ \pm 2 \\ \pm 2.4 \end{gathered}$ | nA $n A$ $n A$ $n A$ |
|  | Input Noise Voltage (Note 10) | $\begin{aligned} & 0.1 \mathrm{~Hz} \text { to } 10 \mathrm{~Hz}, \mathrm{G}=1 \\ & 0.1 \mathrm{~Hz} \text { to } 10 \mathrm{~Hz}, \mathrm{G}=1000 \end{aligned}$ |  |  | $\begin{gathered} 2 \\ 0.2 \end{gathered}$ |  |  | $\begin{gathered} 2 \\ 0.2 \end{gathered}$ |  | $\begin{aligned} & \mu V_{\text {P-P }} \\ & \mu \mathrm{V}_{\text {P-P }} \end{aligned}$ |

Total RTI Noise $=\sqrt{e_{n i}{ }^{2}+\left(e_{n 0} / G\right)^{2}}$ (Note 10)

| $\mathrm{e}_{\text {ni }}$ | Input Noise Voltage Density | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 7 |  | 7 | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{e}_{\text {no }}$ | Output Noise Voltage Density | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 65 |  | 65 | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
|  | Input Noise Current | 0.1 Hz to 10Hz |  |  | 10 |  | 10 | pAp-p |
| $\mathrm{i}_{n}$ | Input Noise Current Density | $\mathrm{f}=1 \mathrm{kHz}$ |  |  | 200 |  | 200 | $\mathrm{fA} / \sqrt{\mathrm{Hz}}$ |
| $\mathrm{R}_{\text {IN }}$ | Input Resistance | $\mathrm{V}_{\text {IN }}=-12.6 \mathrm{~V}$ to 13V |  |  | 225 |  | 225 | G $\Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Differential Common Mode | $\begin{aligned} & f=100 \mathrm{kHz} \\ & f=100 \mathrm{kHz} \end{aligned}$ |  |  | $\begin{gathered} \hline 0.9 \\ 15.9 \end{gathered}$ |  | $\begin{gathered} \hline 0.9 \\ 15.9 \end{gathered}$ | pF pF |
| $\overline{\mathrm{V}} \mathrm{CM}$ | Input Voltage Range | Guaranteed by CMRR | $\bullet$ | $\mathrm{V}^{-}+1.8 / \mathrm{V}^{+}-1.4$ | 8/ $\mathrm{V}^{+}-1.4$ $\mathrm{~V}^{+}-2$ | $\mathrm{V}^{-}+1.8 / \mathrm{V}^{+}-1.4$ |  | V V |
| CMRR | Common Mode Rejection Ratio | DC to 60Hz, 1k Source Imbalance, $V_{\text {CM }}=-12.6 \mathrm{~V}$ to 13 V $G=1$ $G=1$ $G=10$ $G=10$ $G=100$ $G=100$ $G=1000$ $G=1000$ | $\bullet \bullet$ | $\begin{gathered} 94 \\ 87 \\ 112 \\ 106 \\ 126 \\ 120 \\ 134 \\ 122 \end{gathered}$ | $\begin{aligned} & 112 \\ & 132 \\ & 144 \\ & 148 \end{aligned}$ | $\begin{gathered} 88 \\ 83 \\ 110 \\ 104 \\ 120 \\ 114 \\ 130 \\ 120 \end{gathered}$ | $\begin{aligned} & 112 \\ & 132 \\ & 144 \\ & 148 \end{aligned}$ | $d B$ $d B$ $d B$ $d B$ $d B$ $d B$ $d B$ $d B$ |
|  | AC Common Mode Rejection Ratio | $\begin{aligned} & f=20 \mathrm{kHz}, \text { DD10 Package } \\ & G=1 \\ & G=10 \\ & G=100 \\ & G=1000 \end{aligned}$ |  |  |  |  | $\begin{gathered} 77 \\ 98 \\ 135 \\ 128 \end{gathered}$ | dB dB dB dB |
|  |  | $\begin{aligned} & f=20 \mathrm{kHz}, \text { MS8 Package } \\ & f=20 \mathrm{kHz}, \text { S8E Package } \\ & G=1 \\ & G=10 \\ & G=100 \\ & G=1000 \end{aligned}$ |  |  | $\begin{gathered} 71 \\ 91 \\ 101 \\ 103 \end{gathered}$ |  | $\begin{gathered} 71 \\ 91 \\ 101 \\ 103 \end{gathered}$ | $d B$ $d B$ $d B$ $d B$ |

ELECTRICAL CHARACTERISTICS The • denotes the specifications which apply over the specified temperature range, otherwise specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C} . \mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$.

| SYMBOL | PARAMETER | CONDITIONS |  | LT6370A |  |  | LT6370 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | MIN | TYP | MAX | MIN | TYP | MAX |  |
| PSRR | Power Supply Rejection Ratio | $\begin{aligned} & V= \pm 2.375 \mathrm{~V} \text { to } \pm 17.5 \mathrm{~V} \\ & G=1 \\ & G=1 \\ & G=10 \\ & G=10 \\ & G=100 \\ & G=100 \\ & G=1000 \\ & G=1000 \end{aligned}$ | $\bullet \bullet$ | $\begin{aligned} & 116 \\ & 114 \\ & 134 \\ & 124 \\ & 136 \\ & 125 \\ & 136 \\ & 125 \end{aligned}$ | $\begin{aligned} & 130 \\ & 140 \\ & 142 \\ & 146 \end{aligned}$ |  | $\begin{aligned} & 110 \\ & 106 \\ & 130 \\ & 120 \\ & 130 \\ & 120 \\ & 130 \\ & 120 \end{aligned}$ | $\begin{aligned} & 130 \\ & 140 \\ & 142 \\ & 146 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ |
| $\mathrm{V}_{\text {S }}$ | Supply Voltage | Guaranteed by PSRR | $\bullet$ | 4.75 |  | 35 | 4.75 |  | 35 | V |
| $I_{S}$ | Supply Current | $\begin{aligned} & V_{S}= \pm 15 \mathrm{~V} \\ & T_{A}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ | $\bullet$ |  | 2.65 | $\begin{gathered} 2.75 \\ 2.9 \\ 3 \\ \hline \end{gathered}$ |  | 2.65 | $\begin{gathered} 2.75 \\ 2.9 \\ 3 \\ \hline \end{gathered}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \\ & \hline \end{aligned}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}= \pm 2.375 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 85^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ | $\bullet$ |  | 2.55 | $\begin{gathered} \hline 2.6 \\ 2.75 \\ 2.85 \end{gathered}$ |  | 2.55 | $\begin{gathered} 2.6 \\ 2.75 \\ 2.85 \end{gathered}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~mA} \end{aligned}$ |
| $\overline{V_{\text {OUT }}}$ | Output Voltage Swing | $\mathrm{V}_{S}= \pm 15 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\bullet$ | $\begin{aligned} & \hline-14.5 \\ & -14.3 \end{aligned}$ | -14.9/14 | $\begin{aligned} & 13.7 \\ & 13.6 \end{aligned}$ | $\begin{aligned} & \hline-14.5 \\ & -14.3 \end{aligned}$ | -14.9/14 | $\begin{aligned} & 13.7 \\ & 13.6 \end{aligned}$ | V |
|  |  | $\mathrm{V}_{\mathrm{S}}= \pm 2.375 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\bullet$ | $\begin{gathered} -2 \\ -1.8 \end{gathered}$ | -2.3/1.6 | $\begin{aligned} & 1.5 \\ & 1.3 \end{aligned}$ | $\begin{gathered} \hline-2 \\ -1.8 \end{gathered}$ | -2.3/1.6 | $\begin{aligned} & 1.5 \\ & 1.3 \end{aligned}$ | V |
| IOUT | Output Short Circuit Current |  | $\bullet$ | $\begin{aligned} & 35 \\ & 30 \end{aligned}$ | 55 |  | $\begin{aligned} & 35 \\ & 30 \end{aligned}$ | 55 |  | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| BW | -3dB Bandwidth | $\begin{aligned} & \mathrm{G}=1 \\ & \mathrm{G}=10 \\ & \mathrm{G}=100 \\ & \mathrm{G}=1000 \end{aligned}$ |  |  | $\begin{gathered} 3100 \\ 1150 \\ 184 \\ 19 \end{gathered}$ |  |  | $\begin{gathered} 3100 \\ 1150 \\ 184 \\ 19 \end{gathered}$ |  | $\begin{aligned} & \mathrm{kHz} \\ & \mathrm{kHz} \\ & \mathrm{kHz} \\ & \mathrm{kHz} \end{aligned}$ |
| SR | Slew Rate | $G=1, V_{\text {OUT }}= \pm 10 \mathrm{~V}$ | $\bullet$ | $\begin{aligned} & 8 \\ & 6 \end{aligned}$ | 11 |  | $\begin{aligned} & 8 \\ & 6 \end{aligned}$ | 11 |  | V/ $/ \mathrm{s}$ <br> $\mathrm{V} / \mathrm{\mu s}$ |
| $\mathrm{t}_{\mathrm{S}}$ | Settling Time | $\begin{aligned} & \text { 20V Output Step to } 0.0015 \% \\ & G=1 \\ & G=10 \\ & G=100 \\ & G=1000 \end{aligned}$ |  |  | $\begin{gathered} 5.8 \\ 9.8 \\ 16 \\ 100 \end{gathered}$ |  |  | $\begin{gathered} 5.8 \\ 9.8 \\ 16 \\ 100 \\ \hline \end{gathered}$ |  | $\mu \mathrm{S}$ $\mu \mathrm{S}$ $\mu \mathrm{S}$ $\mu \mathrm{S}$ |
| $\mathrm{R}_{\text {REFIN }}$ | REF Input Resistance |  |  |  | 20 |  |  | 20 |  | $\mathrm{k} \Omega$ |
| $\mathrm{I}_{\text {REFIN }}$ | REF Input Current | $\mathrm{V}_{+1 \mathrm{~N}}=\mathrm{V}_{- \text {II }}=\mathrm{V}_{\text {REF }}=0 \mathrm{~V}$ | $\bullet$ | $\begin{aligned} & -40 \\ & -60 \end{aligned}$ | $-27$ | $\begin{gathered} -14 \\ 6 \end{gathered}$ | $\begin{aligned} & -40 \\ & -60 \end{aligned}$ | $-27$ | $\begin{gathered} -14 \\ 6 \end{gathered}$ | $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {REF }}$ | REF Voltage Range |  | $\bullet$ | $\mathrm{V}^{-}$ |  | $\mathrm{V}^{+}$ | V- |  | $\mathrm{V}^{+}$ | V |
| AVREF | REF Gain to Output | $V_{\text {REF }}= \pm 10 \mathrm{~V}$ |  |  | 1 |  |  | 1 |  | V/V |
|  | REF Gain Error | $\mathrm{V}_{\text {REF }}= \pm 10 \mathrm{~V}$ | $\bullet$ | $\begin{aligned} & \hline-80 \\ & -95 \end{aligned}$ | $\overline{-20}$ | $\begin{aligned} & 40 \\ & 55 \end{aligned}$ | $\begin{aligned} & \hline-100 \\ & -115 \end{aligned}$ | $-20$ | $\begin{aligned} & 60 \\ & 75 \end{aligned}$ | ppm <br> ppm |

## ELECTRICAL CHARACTERISTICS

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.
Note 2: Gains higher than 1000 are possible but the resulting low $R_{G}$ values can make PCB and package lead resistance a significant error source.
Note 3: Gain tests are performed with -IN at mid-supply and +IN driven.
Note 4: When the gain is greater than 1 the gain error and gain drift specifications do not include the effect of external gain set resistor $R_{G}$.
Note 5: This specification is guaranteed by design.
Note 6: This specification is guaranteed with high-speed automated testing on the LT6370A. This specification is guaranteed by design and characterization on the LT6370.

Note 7: This parameter is measured in a high speed automatic tester that does not measure the thermal effects with longer time constants. The
magnitude of these thermal effects are dependent on the package used, PCB layout, heat sinking and air flow conditions.
Note 8: For more information on how offsets relate to the amplifiers, see section "Input and Output Offset Voltage" in the Applications section.
Note 9: Hysteresis in output voltage is created by mechanical stress that differs depending on whether the IC was previously at a higher or lower temperature. Output voltage is always measured at $25^{\circ} \mathrm{C}$, but the IC is cycled to the hot or cold temperature limit before successive measurements. Hysteresis is roughly proportional to the square of the temperature change. For instruments that are stored at well controlled temperatures (within 20 or 30 degrees of operational temperature), hysteresis is usually not a significant error source. Typical hysteresis is the worst case of $25^{\circ} \mathrm{C}$ to cold to $25^{\circ} \mathrm{C}$ or $25^{\circ} \mathrm{C}$ to hot to $25^{\circ} \mathrm{C}$, preconditioned by one thermal cycle.
Note 10: Referred to the input.

## TYPICAL PGRFORMAOCE CHARACTERISTICS

$V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.


Distribution of Input Offset Voltage, MS8 Package


6370 G04

## Distribution of Output Offset Voltage, MS8 Package



## Distribution of Input Offset Voltage, S8E Package



Distribution of Input Offset
Voltage Drift, S8E Package


Distribution of Output Offset Voltage, S8E Package


Distribution of Input Offset Voltage, DD10 Package


Distribution of Input Offset Voltage Drift, DD10 Package


Distribution Output Offset Voltage, DD10 Package


TYPICAL PERFORMANCE CHARACTERISTICS
$\mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\text {REF }}=\mathrm{OV}, \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.


6370 G10

## Distribution of Output Offset Voltage Drift, S8E Package



6370 G11

Distribution of Output Offset Voltage Drift, DD10 Package


6370 G12

## Distribution of REF Gain Error




6370 G16

Gain Drift ( $\mathbf{G}=\mathbf{1 0 0 0}$ )


REF Gain Drift


## TYPICAL PERFORMANCE CHARACTERISTICS

$V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.

Gain Nonlinearity ( $G=1$ )


OUTPUT VOLTAGE (2V/DIV)

## 6370 G19

## Gain Nonlinearity ( $\mathbf{G}=\mathbf{1 0 0 0}$ )



OUTPUT VOLTAGE (2V/DIV)

Gain Nonlinearity ( $\mathbf{G}=\mathbf{1 0}$ )


OUTPUT VOLTAGE (2V/DIV)
6370 G20

Gain Nonlinearity ( $\mathbf{G}=\mathbf{1 0 0}$ )


OUTPUT VOLTAGE (2V/DIV)
6370 G21

CMRR vs Frequency, RTI MS8 Package


6370 G24


6370 G25

CMRR vs Frequency, RTI


## TYPICAL PERFORMANCE CHARACTERISTICS

$\mathrm{V}_{\mathrm{S}}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.

0.1 Hz to 10 Hz Voltage Noise, $\mathrm{G}=\mathbf{1 0}$, RTI


TIME (1s/DIV)

### 0.1Hz to 10 Hz Noise Current, Unbalanced Source R



TIME (1s/DIV)

Current Noise Density vs Frequency

0.1 Hz to 10 Hz Voltage Noise,

G = 100, RTI


TIME (1s/DIV)
0.1 Hz to 10 Hz Noise Current, Balanced Source R

0.1 Hz to 10 Hz Voltage Noise,
$\mathrm{G}=1$, RTI

0.1 Hz to 10 Hz Voltage Noise, $\mathrm{G}=1000$, RTI


TIME (1s/DIV)
6370 G33

EMIRR vs Frequency, RTI


## TYPICAL PERFORMANCE CHARACTERISTICS

$V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.


TYPICAL PERFORMANCG CHARACTERISTICS
$V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\text {REF }}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.









## TYPICAL PERFORMANCE CHARACTERISTICS

$V_{S}= \pm 15 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{REF}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k}$, unless otherwise noted.


## PIn FUNCTIONS

(MS/DFN/SOIC)
$-R_{G}$ (Pin 1/Pin 1/Pin 1): For use with an external gain setting resistor.
-IN (Pin 2/Pin 3/Pin 2): Negative Input Terminal. This input is high impedance.
+IN (Pin 3/Pin 4/Pin 3): Positive Input Terminal. This input is high impedance.
$\mathbf{V}^{-}$(Pin 4/Pin 5/Pin 4): Negative Power Supply. A bypass capacitor should be used between supply pins and ground.

REF (Pin 5/Pin 6/Pin 5): Reference for the output voltage. OUTPUT (Pin 6/Pin 7/Pin 6): Output voltage referenced to the REF pin.
V+ (Pin 7/Pin 8/Pin 7): Positive Power Supply. A bypass capacitor should be used between supply pins and ground.
${ }^{+} \mathbf{R}_{\mathbf{G}}$ (Pin 8/Pin 10/Pin 8): For use with an external gain setting resistor.
NC (DFN Pins 2, 9): No Internal Connection.

## SIMPLIFIED BLOCK DIAGRAm



## THEORY OF OPERATION

The LT6370 is an improved version of the classic three op amp instrumentation amplifier topology. Laser trimming and proprietary monolithic construction allow for tight matching and extremely low drift of circuit parameters over the specified temperature range. Refer to the Simplified Block Diagram to aid in understanding the following circuit description. The collector currents in Q1 and Q2 as well as I1 and I4 are trimmed to minimize input offset voltage drift, thus assuring a high level of performance. R1 and R2 are trimmed to an absolute value of 12.1 k to assure that the gain can be set accurately ( $0.08 \%$ at $G=100$ ) with only one external resistor, $R_{G}$. The value of $R_{G}$ determines the transconductance of the preamp stage. As $R_{G}$ is reduced to increase the programmed gain, the transconductance of the input preamp stage also increases to that of the input transistors Q1 and Q2. This causes the open-loop gain to increase when the programmed gain is increased, reducing the input related errors and noise. The input voltage noise at high gains is determined only by Q1 and Q2. At lower gains the noise of the difference amplifier and preamp gain setting resistors may increase the noise. The gain bandwidth product is determined by $\mathrm{C} 1, \mathrm{C} 2$ and the preamp transconductance, which increases with programmed gain. Therefore, the bandwidth is self-adjusting and does not drop directly proportional to gain.
The input transistors Q1 and Q2 offer excellent matching, drift and noise performance, which is due to using a proprietary high performance process, as well as low input bias current due to the high beta of these input devices. The input bias current is further reduced by trimming I3 and I6. The collector currents in Q1 and Q2 are held constant due to the feedback through the Q1-A1-R1 loop and Q2-A2-R2 loop. The action of the amplifier loops impresses the differential input voltage across the external gain set resistor $R_{G}$. Since the current that flows through $\mathrm{R}_{\mathrm{G}}$ also flows through R1 and R2, the ratios provide a gained-up differential voltage,

$$
G=1+\frac{R 1+R 2}{R_{G}}
$$

to the difference amplifier A3. The difference amplifier removes the common mode voltage and provides a single-ended output voltage referenced to the voltage on the REF pin. The offset voltage of the difference amplifier is trimmed to minimize output offset voltage drift, thus assuring a high level of performance, even in low gains. Resistors R5 to R8 are trimmed to maximize CMRR and minimize gain error. The resulting gain equation is:

$$
G=1+\frac{24.2 k}{R_{G}}
$$

Solving for the gain set resistor gives:

$$
\mathrm{R}_{\mathrm{G}}=\frac{24.2 \mathrm{k}}{\mathrm{G}-1}
$$

Table 1 shows appropriate $1 \%$ resistor values for a variety of gains.

Table 1. LT6370 Gain and $\mathrm{R}_{\mathrm{G}}$ Lookup.

| Resulting Gains for Various 1\% Standard Resistor Values |  |
| :---: | :---: |
| Gain | Standard 1\% Resistor Value ( $\mathbf{\Omega}$ ) |
| 1 | - |
| 1.996 | 24.3 k |
| 5.007 | 6.04 k |
| 10.06 | 2.67 k |
| 20.06 | 1.27 k |
| 50.69 | 487 |
| 100.6 | 243 |
| 201 | 121 |
| 497.9 | 48.7 |
| 996.9 | 24.3 |


| Convenient Integer Gains Using Various Standard 1\% Resistor Values |  |
| :---: | :---: |
| Integer Gain | Standard 1\% Resistor Value $\boldsymbol{(} \boldsymbol{\Omega})$ |
| 1 | - |
| 3 | 12.1 k |
| 21 | 1.21 k |
| 23 | 1.1 k |
| 122 | 200 |
| 201 | 121 |
| 221 | 110 |
| 243 | 100 |
| 1211 (Note 2) | 20 |

## LT6370

## APPLICATIONS INFORMATION

## Valid Input and Output Range

Instrumentation amplifiers traditionally specify a valid input common mode range and an output swing range. This however often fails to identify limitations associated with internal swing limits. Referring to the Simplified





Block Diagram, the output swing of pre-amplifiers A1 and A2 as well as the common-mode input range of the difference amplifier A3 impose limitations on the valid operating range. The following graphs show the operating region where a valid output is produced.

6370 F0 1

Figure 1. Input Common Mode Range vs Output Voltage

## APPLICATIONS INFORMATION






370 F01j


Figure 1 (Continued). Input Common Mode Range vs Output Voltage

## APPLICATIONS INFORMATION

## REF Pin

The REF pin has a nominal gain of 1 to the output. Resistance in series with the REF pin must be minimized to preserve high common mode rejection. For example, a series resistance of $2 \Omega$ from the REF pin to ground will not only increase the gain error by $0.02 \%$ but will lower the CMRR to 80 dB . If this pin is driven by an amplifier as shown in Figure 2, the closed-loop output impedance of this amplifier at the desired frequency must also be low to avoid degrading the AC CMRR shown in the typical curves section.

It is also important to note that the drift in the circuitry used to drive the REF pin will result in an additional output drift term. Therefore, it may be important to consider the temperature accuracy of the circuitry used to drive the REF pin.


Figure 2. Buffering the REF Pin

## Input and Output Offset Voltage

The offset voltage of the LT6370 has two main components: the input offset voltage due to the input amplifiers and the output offset due to the output amplifier. The total offset voltage referred to the input (RTI) is found by dividing the output offset by the programmed gain and adding it to the input offset voltage. At high gains the input offset voltage dominates, whereas at low gains the output offset voltage dominates. The total offset voltage is:
Total input offset voltage (RTI) $=\mathrm{V}_{\mathrm{OSI}}+\mathrm{V}_{\mathrm{OSO}} / \mathrm{G}$
Total output offset voltage (RTO) $=\mathrm{V}_{\text {OSI }} \bullet \mathrm{G}+\mathrm{V}_{\text {OSO }}$
The preceding equations can also be used to calculate offset drift in a similar manner.

## Output Offset Trimming

The LT6370 is laser trimmed for low offset voltage so that no external offset trimming is required for most applications. In the event that the offset voltage needs to be adjusted, the circuit in Figure 3 is an example of an optional offset adjustment circuit. The op amp buffer provides a low impedance signal to the REF pin in order to achieve the best CMRR and lowest gain error.


Figure 3. Optional Trimming of Output Offset Voltage

## Thermocouple Effects

In order to achieve accuracy on the microvolt level, thermocouple effects must be considered. Any connection of dissimilar metals forms a thermoelectric junction and generates a small temperature-dependent voltage. Also known as the Seebeck Effect, these thermal EMFs can be the dominant error source in low-drift circuits.

Connectors, switches, relay contacts, sockets, resistors, and solder are all candidates for significant thermal EMF generation. Even junctions of copper wire from different manufacturers can generate thermal EMFs of $200 \mathrm{nV} /{ }^{\circ} \mathrm{C}$, which is comparable to the maximum input offset voltage drift specification of the LT6370. Figures 4 and 5 illustrate the potential magnitude of these voltages and their sensitivity to temperature.

In order to minimize thermocouple-induced errors, attention must be given to circuit board layout and component selection. It is good practice to minimize the number of junctions in the amplifier's input and $\mathrm{R}_{\mathrm{G}}$ signal paths and avoid connectors, sockets, switches, and relays whenever possible. If such components are required, they should be

## APPLICATIONS INFORMATION

selected for low thermal EMF characteristics. Furthermore, the number, type, and layout of junctions should be matched for both inputs with respect to thermal gradients on the circuit board. Doing so may involve deliberately introducing dummy junctions to offset unavoidable junctions.
Air currents can also lead to thermal gradients and cause significant noise in measurement systems. It is important to prevent airflow across sensitive circuits. Doing so will often reduce thermocouple noise substantially. Placing PCB input traces close together, and on an internal PCB layer, can help minimize temperature differentials resulting from air currents reacting with the input trace thermal surface area.


Figure 4. Thermal EMF Generated by Two Copper Wires From Different Manufacturers


Figure 5. Solder-Copper Thermal EMFs

## Reducing Board-Related Leakage Effects

Leakage currents can have a significant impact on system accuracy, particularly in high temperature and high voltage applications. Quality insulation materials should be used, and insulating surfaces should be cleaned to remove fluxes and other residues. For humid environments, surface coating may be necessary to provide a moisture barrier.

Leakage into the $\mathrm{R}_{\mathrm{G}}$ pin conducts through the on-chip feedback resistor, creating an error at the output of the pre-amplifiers. This error is independent of gain and degrades accuracy the most at low gains. This leakage can be minimized by encircling the $\mathrm{R}_{\mathrm{G}}$ connections with a guard-ring operated at a potential very close to that of the $\mathrm{R}_{\mathrm{G}}$ pins. The DFN package has NC pins adjacent to each $\mathrm{R}_{\mathrm{G}}$ pin which can be used to simplify the implementation of this guard-ring. These NC pins do not provide any bias and have no internal connections. In some cases, the guard-ring can be connected to the input voltage which biases one diode drop below $\mathrm{R}_{\mathrm{G}}$.


Figure 6. Guard-Rings Can Be Used to Minimize Leakage into the $\mathrm{R}_{\mathbf{G}}$ Pins
Leakage into the input pins reacts with the source resistance, creating an error directly at the input. This leakage can be minimized by encircling the input connections with a guard-rings operated at a potential very close to that of the input pins. In some cases, the guard-ring can be connected to $R_{G}$ which biases one diode above the input.


Figure 7. Guard-Rings Can Be Used to Minimize Leakage into the Input Pins

## APPLICATIONS INFORMATION




CENTER-TAP PROVIDES BIAS CURRENT RETURN

6370 F08

Figure 8. Providing an Input Common Mode Current Path

For the lowest leakage, amplifiers can be used to drive the guard ring. These buffers must have very low input bias current since that will now be a leakage.

## Input Bias Current Return Path

The low input bias current of the LT6370 (400pA max) and high input impedance ( $225 \mathrm{G} \Omega$ ) allow the use of high impedance sources without introducing additional offset voltage errors, even when the full common mode range is required. However, a path must be provided for the input bias currents of both inputs when a purely differential signal is being amplified. Without this path, the inputs will float to either rail and exceed the input common mode range of the LT6370, resulting in a saturated input amplifier. Figure 8 shows three examples of an input bias current path. The first example is of a purely differential signal source with a $10 \mathrm{k} \Omega$ input current path to ground. Since the impedance of the signal source is low, only one resistor is needed. Two matching resistors are needed for higher impedance signal sources as shown in the second example. Balancing the input impedance improves both $A C$ and $D C$ common mode rejection and $D C$ offset. The need for input resistors is eliminated if a center tap is present as shown in the third example.

## Input Protection

Additional input protection can be achieved by adding external resistors in series with each input. If low value resistors are needed, a clamp diode from the positive supply to each input will help improve robustness. A 2N4394 drain/source to gate is a good low leakage diode which can be used as shown in Figure 9. Robust input resistors should be chosen, such as carbon composite or bulk metal foil. Metal film and carbon film should not be used because of their poor performance.


Figure 9. Input Protection

## Maintaining AC CMRR

To achieve optimum AC CMRR, it is important to balance the capacitance on the $R_{G}$ gain setting pins. Furthermore, if the source resistance on each input is not equal, adding an additional resistance to one input to improve input source resistance matching will improve AC CMRR.

## APPLICATIONS INFORMATION

## RFI Reduction/Internal RFI Filter

In many industrial and data acquisition applications, the LT6370 will be used to amplify small signals accurately in the presence of large common mode voltages or high levels of noise. Typically, the sources of these very small signals (on the order of microvolts or millivolts) are sensors that can be a significant distance from the signal conditioning circuit. Although these sensors may be connected to signal conditioning circuitry using shielded or unshielded twisted-pair cabling, the cabling may act as an antenna, conveying very high frequency interference directly into the input stage of the LT6370.

The amplitude and frequency of the interference can have an adverse effect on an instrumentation amplifier's input stage by causing any unwanted DC shift in the amplifier's input offset voltage. This well known effect is called RFI rectification and is produced when out-of-band interference is coupled (inductively, capacitively or via radiation) and rectified by the instrumentation amplifier's input transistors. These transistors act as high frequency signal detectors, in the same way diodes were used as RF envelope detectors in early radio designs. Regardless of the type of interference or the method by which it is coupled into the circuit, an out-of-band error signal appears in series with the instrumentation amplifier's inputs.

To help minimize this effect, the LT6370 has 50MHz onchip RFI filters to help attenuate high frequencies before they can interact with its input transistors. These on-chip filters are well matched due to their monolithic construction, which helps minimize any degradation in AC CMRR. To reduce the effect of these out-of-band signals on the input offset voltage of the LT6370 further, an additional external low-pass filter can be used at the inputs. The filter should be located very close to the input pins of the circuit. An effective filter configuration is illustrated in Figure 10, where three capacitors have been added to the inputs of the LT6370.

The filter limits the input signal according to the following relationship:
FilterFreq $_{\text {DIFF }}=\frac{1}{2 \pi R\left(2 C_{D}+C_{C}\right)}$

FilterFreq $_{C M}=\frac{1}{2 \pi \mathrm{RC}_{\mathrm{C}}}$
where $C_{D} \geq 10 C_{C}$.
$C_{D}$ affects the difference signal. $C_{C}$ affects the commonmode signal. Any mismatch in $\mathrm{R} \times \mathrm{C}_{\mathrm{C}}$ degrades the LT6370 CMRR. To avoid inadvertently reducing CMRR-bandwidth performance, make sure that $\mathrm{C}_{\mathrm{C}}$ is at least one order of magnitude smaller than $\mathrm{C}_{\mathrm{D}}$. The effect of mismatched $\mathrm{C}_{C} S$ is reduced with a larger $C_{D}: C_{C}$ ratio.


Figure 10. Adding a Simple External RC Filter at the Inputs to an Instrumentation Amplifier Is Effective in Further Reducing Rectification of High Frequency Out-Of-Band Signals.
To avoid any possibility of common mode to differential mode signal conversion, match the common mode lowpass filter on each input to $1 \%$ or better. Here are the steps to help determine appropriate values for the filter:

1. Pick $R$ and $C_{D}$ to have a low pass pole at least $10 x$ higher than the highest signal of interest (e.g. 500 Hz for a 50 Hz signal) using:

$$
\begin{aligned}
\text { FilterFreq }_{\text {DIFF }} & =\frac{1}{2 \pi R\left(2 C_{D}+C_{C}\right)} \\
& =\frac{1}{2 \pi R\left(2 C_{D}+0.1 C_{D}\right)} \\
& =\frac{1}{4.2 \pi R C_{D}}
\end{aligned}
$$

2. Select $C_{C}=C_{D} / 10$.

## APPLICATIONS INFORMATION

If implemented this way, the common-mode pole frequency is placed about 20x higher than the differential pole frequency. Here are the differential and commonmode low pass pole frequencies for the values shown in Figure 10:

## FilterFreq ${ }_{\text {DIFF }}=500 \mathrm{~Hz}$

FilterFreq ${ }_{c m}=10 \mathrm{kHz}$

## Error Budget Analysis

The LT6370 offers performance superior to that of competing monolithic instrumentation amplifiers. A typical application that amplifies and buffers a bridge transducer's differential output is shown in Figure 11. The amplifier is set to a gain of 100 and amplifies a differential, full-scale transducer's output voltage of 20 mV over the industrial temperature range. The LT6370 will be compared to other monolithic instrumentation amplifiers. As
shown, the LT6370 outperforms these other instrumentation amplifiers. The error budget comparison in Table 2 shows how various errors are calculated and how each error affects the total error budget. The table shows the clear benefit to low offset voltage, low offset voltage drift and low gain drift.


Figure 11. Precision Bridge Amplifier

Table 2. Error Budget Comparison

| ERROR SOURCE | CALCULATION | ERROR, ppm OF FULL SCALE |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | LT6370A | IA1 | IA2 | IA3 | IA4 | IA5 | IA6 |
| Absolute Accuracy at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  |  |  |  |  |  |  |
| Input Offset Voltage, $\mu \mathrm{V}$ | $\mathrm{V}_{\text {os }} / 20 \mathrm{mV}$ | 1250 | 6250 | 1250 | 3500 | 2500 | 7500 | 3000 |
| Output Offset Voltage, $\mu \mathrm{V}$ | [ $\left.\mathrm{V}_{\text {Oso }} / 100\right] / 20 \mathrm{mV}$ | 83 | 500 | 100 | 300 | 250 | 350 | 150 |
| Input Offset Current, nA | [(los)(350)/2]/20mV | 6.1 | 18 | 3.5 | 17.5 | 43.75 | 43.75 | 4 |
| CMRR, dB | [(CMRR in ppm)(5V)/20mV | 125 | 791 | 79 | 158 | 250 | 250 | 790 |
| Total Accuracy Error |  | 3264.1 | 10059 | 3932.5 | 5975.5 | 9043.75 | 10643.75 | 5744 |
| Drift to $85^{\circ} \mathrm{C}$ <br> Gain Drift, ppm $/{ }^{\circ} \mathrm{C}$ <br> Input Offset Voltage Drift, $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> Output Offset Voltage Drift, $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ | (Gain Drift + 10ppm) $\left(60^{\circ} \mathrm{C}\right)$ $\left[\left(V_{\text {OSI }}\right.\right.$ Drift) $\left.\left(60^{\circ} \mathrm{C}\right)\right] / 20 \mathrm{mV}$ $\left[\left(V_{\text {oso }}\right.\right.$ Drift) $\left.\left(60^{\circ} \mathrm{C}\right)\right] / 100 / 20 \mathrm{mV}$ |  |  |  |  |  |  |  |
|  |  | 2400 | 3600 | 3600 | 5400 | 6600 | 2700 | 3600 |
|  |  | 900 | 3000 | 900 | 2700 | 1500 | 6000 | 1200 |
|  |  | 45 | 450 | 150 | 270 | 600 | 300 | 180 |
| Total Drift Error |  | 3345 | 7050 | 4650 | 8370 | 8700 | 9000 | 4980 |
| Resolution <br> Gain Nonlinearity, ppm of Full Scale <br> Typ 0.1Hz to 10 Hz Voltage Noise, $\mu \mathrm{V}_{\text {P-p }}$ | (0.1Hz to 10Hz Noise)/20mV |  |  |  |  |  |  |  |
|  |  | 30 | 40 | 15 | 10 | 20 | 5 | 15 |
|  |  | 10 | 14 | 12.5 | 3.5 | 10 | 26 | 14 |
| Total Resolution Error |  | 40 | 54 | 27.5 | 13.5 | 30 | 31 | 29 |
| Grand Total Error |  | 6649.1 | 17163 | 8610 | 14359 | 17773.8 | 19674.8 | 10753 |

$G=100$
All errors are min/max and referred to input.

## TYPICAL APPLICATIONS

Differential Output Instrumentation Amplifier


TYPICAL APPLICATIONS
Precision Voltage-to-Current Converter


High Side, Bidirectional Current Sense


## PACKAGE DESCRIPTION

## S8E Package

8-Lead Plastic SOIC (Narrow . 150 Inch) Exposed Pad
(Reference LTC DWG \# 05-08-1857 Rev C)


## MS8 Package <br> 8-Lead Plastic MSOP

(Reference LTC DWG \# 05-08-1660 Rev G)


## PACKAGE DESCRIPTION

## DD Package

10-Lead Plastic DFN ( $3 \mathrm{~mm} \times 3 \mathrm{~mm}$ )
(Reference LTC DWG \# 05-08-1699 Rev C)


RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS


NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE MO-229 VARIATION OF (WEED-2). CHECK THE LTC WEBSITE DATA SHEET FOR CURRENT STATUS OF VARIATION ASSIGNMENT
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

## LT6370

## TYPICAL APPLICATION

Remote Strain Gauge Amplifier


## RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
| :---: | :---: | :---: |
| Instrumentation Amplifiers |  |  |
| AD8429 | Low Noise Instrumentation Amplifier | $\mathrm{V}_{S}=36 \mathrm{~V}, \mathrm{I}_{\text {S }}=6.7 \mathrm{~mA}, \mathrm{~V}_{\text {OS }}=50 \mu \mathrm{~V}, \mathrm{BW}=15 \mathrm{MHz}$, eni $=1 \mathrm{nV} / \sqrt{\mathrm{Hz}}$, eno $=45 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| LTC1100 | Zero-Drift Instrumentation Amplifier | $\mathrm{V}_{S}=18 \mathrm{~V}, \mathrm{I}_{\text {S }}=2.4 \mathrm{~mA}, \mathrm{~V}_{0 S}=10 \mu \mathrm{~V}, \mathrm{BW}=19 \mathrm{kHz}, 1.9 \mu \mathrm{~V}$ P-p DC to 10 Hz |
| AD8421 | Low Noise Instrumentation Amplifier | $\mathrm{V}_{S}=36 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=2 \mathrm{~mA}, \mathrm{~V}_{0 S}=25 \mu \mathrm{~V}, \mathrm{BW}=10 \mathrm{MHz}$, eni $=3 \mathrm{nV} / \sqrt{\mathrm{Hz}}$, eno $=60 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| AD8221 | Low Power Instrumentation Amplifier | $V_{S}=36 \mathrm{~V}, \mathrm{I}_{\text {S }}=900 \mu \mathrm{~A}, \mathrm{~V}_{\text {OS }}=25 \mu \mathrm{~V}, \mathrm{BW}=825 \mathrm{kHz}$, eni $=8 \mathrm{nV} / \sqrt{\mathrm{Hzz}}$, eno $=75 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| LT1167 | Instrumentation Amplifier | $\mathrm{V}_{S}=36 \mathrm{~V}, \mathrm{I}_{\text {S }}=900 \mu \mathrm{~A}, \mathrm{~V}_{0 S}=40 \mu \mathrm{~V}, \mathrm{BW}=1 \mathrm{MHz}$, eni $=7.5 \mathrm{nV} / \sqrt{\mathrm{Hzz}}$, eno $=67 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| AD620 | Low Power Instrumentation Amplifier | $V_{S}=36 \mathrm{~V}, \mathrm{I}_{\text {S }}=900 \mu \mathrm{~A}, \mathrm{~V}_{\text {OS }}=50 \mu \mathrm{~V}, \mathrm{BW}=1 \mathrm{MHz}$, eni $=9 \mathrm{nV} / \sqrt{\mathrm{Hz}}$, eno $=72 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| LTC6800 | RRIO Instrumentation Amplifier | $\mathrm{V}_{S}=5.5 \mathrm{~V}, \mathrm{I}_{\text {S }}=800 \mu \mathrm{~A}, \mathrm{~V}_{0 S}=100 \mu \mathrm{~V}, \mathrm{BW}=200 \mathrm{kHz}, 2.5 \mu \mathrm{~V}$ P-P DC to 10 Hz |
| LTC2053 | Zero-Drift Instrumentation Amplifier | $\mathrm{V}_{S}=11 \mathrm{~V}, \mathrm{I}_{S}=750 \mu \mathrm{~A}, \mathrm{~V}_{0 S}=10 \mu \mathrm{~V}, \mathrm{BW}=200 \mathrm{kHz}, 2.5 \mu \mathrm{~V}$ P-P DC to 10 Hz |
| LT1168 | Low Power Instrumentation Amplifier | $V_{S}=36 \mathrm{~V}, \mathrm{I}_{\mathrm{S}}=350 \mu \mathrm{~A}, \mathrm{~V}_{0 S}=40 \mu \mathrm{~V}, \mathrm{BW}=400 \mathrm{kHz}$, eni $=10 \mathrm{nV} / \sqrt{\mathrm{Hz}}$, eno $=165 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ |

## Operational Amplifiers

| LTC2057 | 40 V Zero Drift Op Amp | $\mathrm{V}_{0 S}=4 \mu \mathrm{~V}$, Drift $=15 \mathrm{nV} /{ }^{\circ} \mathrm{C}, \mathrm{I}_{\mathrm{B}}=200 \mathrm{pA}, \mathrm{I}_{\mathrm{S}}=900 \mu \mathrm{~A}$ |
| :--- | :--- | :--- |

## Analog to Digital Converters

| LTC2389-18 | 18-Bit SAR ADC | 2.5Msps, $99.8 \mathrm{~dB} \mathrm{SNR}, 162.5 \mathrm{~mW}$ |
| :--- | :--- | :--- |
| LTC2369-18 | 18-Bit SAR ADC | $1.6 \mathrm{Msps}, 96.5 \mathrm{~dB} \mathrm{SNR}, 18 \mathrm{~mW}$ |

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Instrumentation Amplifiers category:
Click to view products by Analog Devices manufacturer:
Other Similar products are found below :
ADA4254RU-EBZ JM38510/13501BGA MCP6N16-001E/MF LT1102IN8\#PBF AD694BRZ-REEL7 LT1101ISW JM38510/13502BGA AD521JDZ AD521KDZ AD521LDZ AD524ADZ AD524BDZ AD524CDZ AD620ANZ AD621BNZ AD621BR AD622ANZ AD623ANZ AD623BNZ AD624ADZ AD624CDZ AD624SD/883B AD625ADZ AD625BDZ AD625JNZ AD625KNZ AD625SD AD627BNZ AD693AD AD693AE AD693AQ AD694AQ AD694ARZ-REEL AD694BRZ-REEL AD694JNZ AD8221ARMZ-R7 AD8222HBCPZ-WP AD8224ACPZ-R7 AD8224BCPZ-WP AD8224HBCPZ-WP AD8226ARMZ-R7 AD8228ARMZ AD8228ARMZ-R7 AD8229HDZ AD8236ARMZ-R7 AD8237ARMZ-R7 AD8253ARMZ AD8293G160BRJZ-R7 AD8293G80BRJZ-R2 AD8553ARMZ

